

Voltage and Capacitance Analysis of EWOD System Using COMSOL

Debanjan Das¹, Shiraz Sohail¹, Soumen Das², Karabi Biswas¹

¹Department of Electrical Engineering

²School of Medical Science and Technology

IIT Kharagpur, Kharagpur



Content

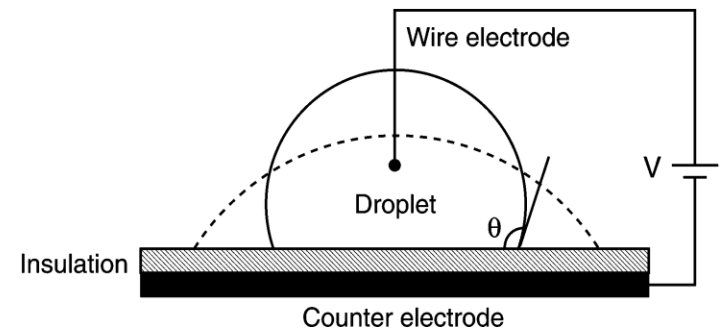
- Introduction
- Motivation and Objective
- Modeling of EWOD system
- Model Definition
- Voltage Distribution
- Effect of Dielectric layer
- Capacitance Analysis
 - Droplet's Position
 - Droplet's Composition
- Conclusion
- References

Digital Microfluidic: State of the Art...

- Manipulation of discrete droplets on an electrode array using electric fields-“**Droplet processors**”
- ElectroWetting On Dielectric (EWOD) has now become one of the best way to manipulate the droplet in DMS
- What is EWOD?
 - **Electrical control of wettability of liquids on a dielectric material**
- Application of V reduces θ due to lowering of the effective solid–liquid interfacial energy

$$\cos \theta = \cos \theta_0 + \frac{\epsilon_0 \epsilon_r}{2d\gamma_{LV}} V^2$$

- Main physics behind EWOD phenomenon is electrostatic energy



Schematic of Traditional EWOD system

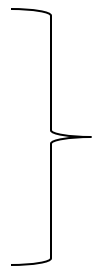


- Advantages of EWOD:

- Has no mechanical part
- Control parameters are in electrical domain
- Can perform all operations on same device by programming
- Easy to fabricate

- Applications:

- Lab-on-a-chip systems
- MEMS-based fluidic devices
- Biomedical devices
- Chip cooling
- Variable focal length lenses



PCR, Enzyme Assays,
Proteomics, DNA
Hybridization

Motivation

- ❑ Idea: Lab-on-a-Chip for clinical diagnoses
 - ❑ Use EWOD phenomenon

- ❑ Problem with EWOD system:
 - May damage the cells with high applied
 - Very often droplet loses its track

- ❑ Understanding of the electrostatic properties
 - Voltage distribution
 - Capacitance

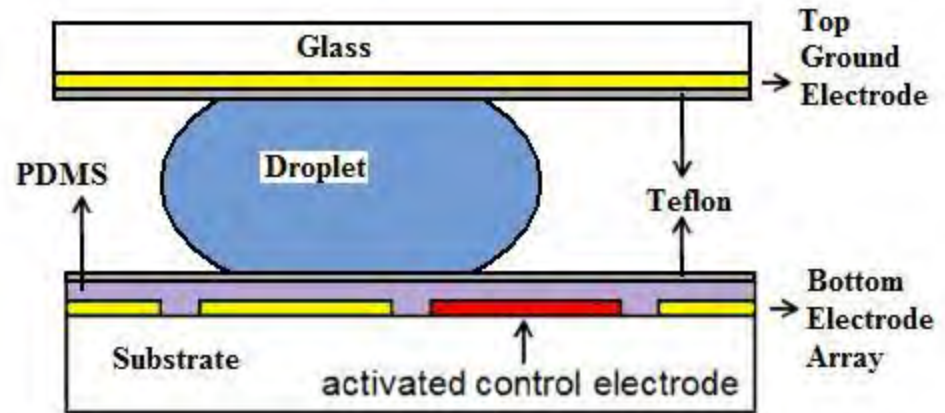
Objective

- Analysis of voltage distribution in EWOD system
 - Applied voltage across test sample

- Modeling and analysis of capacitance
 - Current position of droplet
 - Composition of the sample

Modeling of EWOD System

- EWOD system is very similar to a parallel plate capacitor



- Each addressable position can be modeled as a number of parallel plate capacitors connected in series



Cross section of EWOD system and equivalent electrical circuit

Cont.....

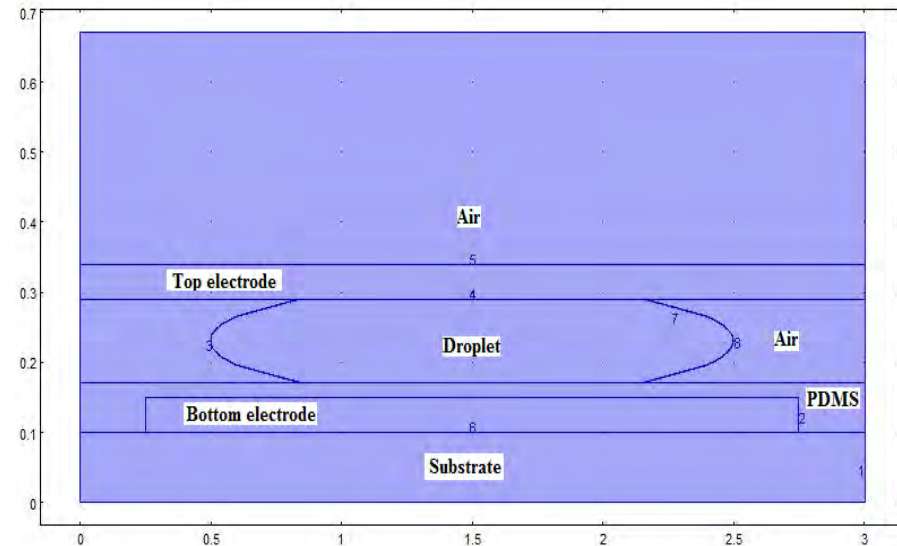
- The equivalent capacitance in each measurement volume:

$$C_{Fi} = \frac{\epsilon_0 \epsilon_T \epsilon_P \epsilon_{Fi} A}{\epsilon_{Fi} (2\epsilon_P t_T + \epsilon_T t_P) + \epsilon_T \epsilon_P t_G}$$

- ϵ is a dielectric constant
- A is the area of the electrode
- t is the thickness
- T , P , G and F_i denote the Teflon layer, the PDMS layer, the gap between the substrates, and the fluid in the measurement volume respectively

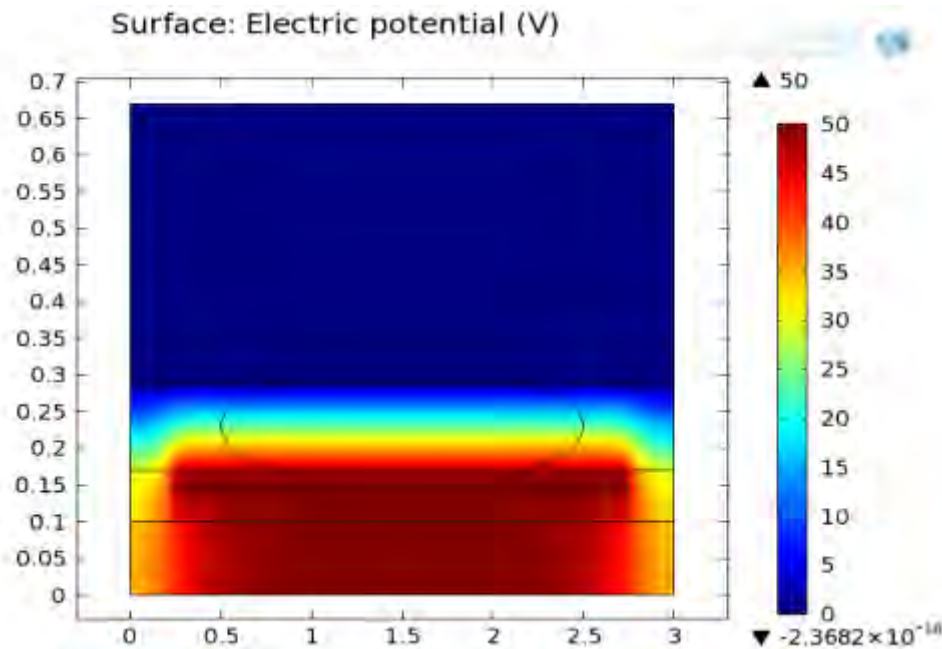
Model Definition

- DC Electrostatic physics under AC/ DC module
- Electrode dimension
 - 2 mm × 50 μm.
- Height between top and bottom electrode is 80 μm.
- PDMS thickness 20 μm
- Dielectric constant
 - Water- 80, Air-1, PDMS- 3
- Boundary condition
 - Ground- Top electrode, Terminal- Bottom electrode



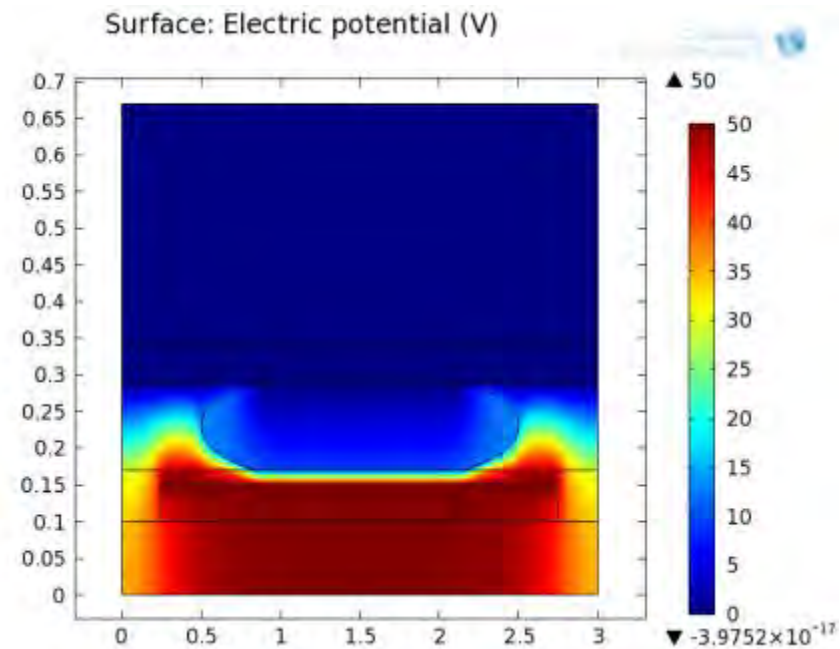
Voltage Distribution

■ Voltage distribution in EWOD system



Air filling the gap

❖ 94.6% voltage drop across the gap



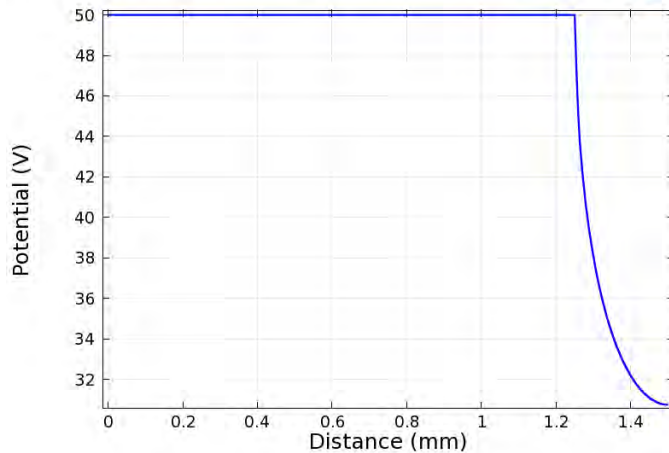
Water filling the gap

❖ 18% voltage drop of total applied potential

Effect of Dielectric layer

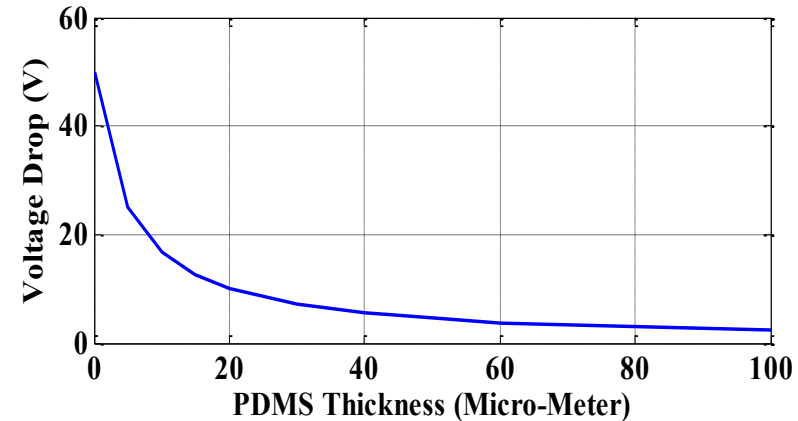
- ❑ Voltage drop decreases with increasing thickness of PDMS

Potential Distribution on Top Surface of PDMS

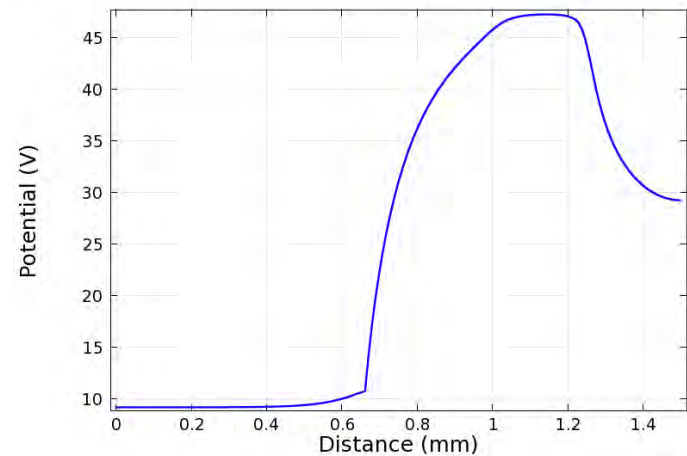


- ❑ A constant voltage drop until the edge of the electrode
- ❑ Maximum voltage drops across the PDMS at the edge of droplet

Voltage Drop Across Droplet with Thickness



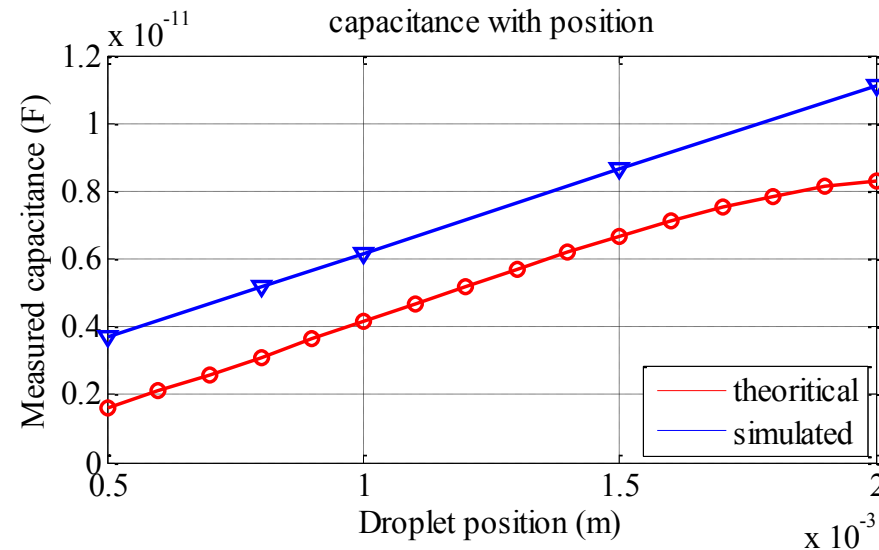
Potential Distribution on Top Surface of PDMS



Capacitance Analysis

□ Monitoring Droplet's Position

- In each position system forms a parallel plate capacitor
- Capacitance value is simulated by changing the droplet's position
- A linear relationship between the capacitance value and droplet position
- By developing a capacitance measurement system its position can be monitored



Capacitance Analysis

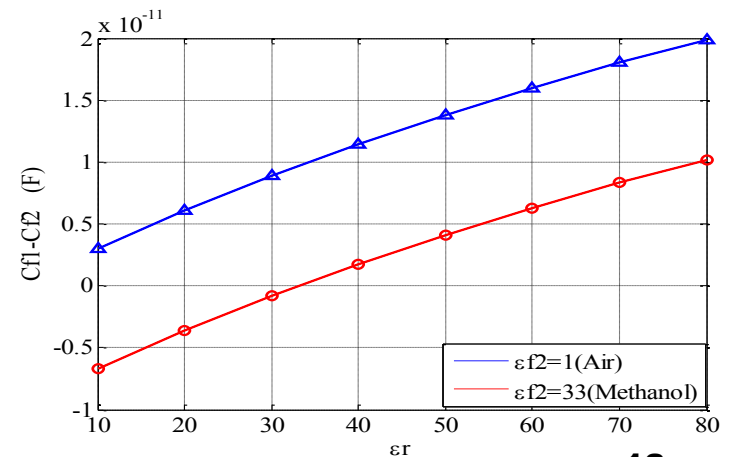
Identifying Droplet's Composition

- Capacitance value differs between fluids and their composition
- Difference between the measured and a reference capacitance

$$C_{F1} - C_{F2} = \frac{\epsilon_0 A}{t_G} \phi(\epsilon_{F1} - \epsilon_{F2})$$

- F1 and F2- fluid being examined and a reference fluid
- Changing of F1 $\implies \epsilon_{F1}$ changes $\implies C_{F1} - C_{F2}$ changes

- Difference gives information of droplet composition or percentage of mixing.



Conclusion

- ❑ Voltage distributions studied with respect to dielectric layer thickness and the position of the droplet
- ❑ Voltage drop observed across the dielectric layer can be reduced by increasing dielectric thickness
- ❑ Lower voltage may protect cells from damage
- ❑ Both simulation and theoretical results show that capacitance value changes linearly with the droplet position
- ❑ Accurate capacitance measurement will give indication about droplet's proper position and idea about percentage of mixing
- ❑ 3-D modeling and inclusion of cell itself in the model are required

Reference

- [1] F Mugele and JC Baret, Electrowetting: from basics to applications, Journal of Physics:Condensed matter, R705 (2005).
- [2] MG Pollack, A.D Shenderov, and R.B Fair, “Electrowetting based Actuation of Droplets for Integrated Microfluidics,” Lab on a Chip, vol. 2, pp. 96-10 (2002).
- [3] Y-H Chang, G-B Lee, F-C Huang, Y-Y Chen, J-L Lin, “Integrated polymerase chain reaction chips utilizing digital microfluidics,” Biomed Microdevices, vol. 8, pp. 215–225 (2006)
- [4] V Srinivasan, VK Pamula, RB Fair, “An integrated digital microfluidic lab-on-a-chip for clinical diagnostics on human physiological fluids,” Lab Chip, vol. 4, pp. 310–315 (2004)..
- [5] J. Berthier, Microdroplets and Digital Microfluidics, William Andrew Inc, Norwich, NY (2008).



Thank you